

# Product Change Notification - GBNG-11DXBN660

**Date:** 31 Aug 2017  
**Product Category:** Interface- Serial Peripherals  
**Notification subject:** CCB 2770 Final Notice: Qualification of CuPdAu bond wire and C194 lead frame material in selected products of the 150K wafer technology available in 20L QFN package at NSEB assembly site.  
**Notification text:** **PCN Status:**  
Final notification

**Microchip Parts Affected:**  
Please open the attachments found in the attachments field below labeled as PCN\_#\_Affected\_CPN.

NOTE: For your convenience Microchip includes identical files in two formats (.pdf and .xls).

**Description of Change:**  
Qualification of palladium coated copper with gold flash (CuPdAu) bond wire and C194 lead frame material in selected products of the 150K wafer technology available in 20L QFN package at NSEB assembly site.

**Pre Change:**  
Using gold (Au) bond wire and EFTEC-64T lead frame material.

**Post Change:**  
Using palladium coated copper with gold flash (CuPdAu) bond wire and C194 lead frame material.

**Pre and Post Change Summary:**

	Pre Change	Post Change
<b>Assembly Site</b>	NSEB assembly site	NSEB assembly site
<b>Wire material</b>	Au wire	CuPdAu wire
<b>Die attach material</b>	8600	8600
<b>Molding compound material</b>	G700LTD	G700LTD
<b>Lead frame material</b>	EFTEC-64T	C194

**Impacts to Data Sheet:**  
None

**Change Impact:**  
None

**Reason for Change:**  
To improve manufacturability by qualifying palladium coated copper with gold flash (CuPdAu) bond wire and C194 lead frame material at NSEB assembly site.

**Change Implementation Status:**  
In Progress

**Estimated First Ship Date:**  
September 16, 2017 (1737)

NOTE: Please be advised that after the estimated first ship date customers may receive pre and post change parts.

**Time Table Summary:**

	October 2016	->	August 2017	September 2017
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Workweek	41	42	43	44		31	32	33	34	35	36	37	38	39
Initial PCN Issue Date			X											
Qual Report Availability								X						
Final PCN Issue Date								X						
Estimated Implementation Date												X		

**Method to Identify Change:**

Traceability code

**Qualification Report:**

Please open the attachments included with this PCN labeled as PCN\_#\_Qual Report.

**Revision History:**

**October 20, 2016:** Issued initial notification.

**August 16, 2017:** Issued final notification. Attached the Qualification Report. Provided estimated first ship date on September 16, 2017

**August 31, 2017:** Re-issued final notification to update subject from Initial Notice to Final Notice.

The change described in this PCN does not alter Microchip's current regulatory compliance regarding the material content of the applicable products.

**Attachment(s):**

[PCN\\_GBNG-11DXBN660\\_Affected\\_CPN.pdf](#)

[PCN\\_GBNG-11DXBN660\\_Qual Report.pdf](#)

[PCN\\_GBNG-11DXBN660\\_Affected\\_CPN.xlsx](#)

Please contact your local [Microchip sales office](#) with questions or concerns regarding this notification.

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Affected Catalog Part Number (CPN)

<b>PCN_GBNG-11DXBN660</b>
<b>CATALOG_PART_NBR</b>
MCP23008-E/ML
MCP23008T-E/ML
MCP23S08-E/ML
MCP23S08T-E/ML



**MICROCHIP**

**QUALIFICATION REPORT SUMMARY**  
RELIABILITY LABORATORY

**PCN #: GBNG-11DXBN660**

**Date**  
**May 25, 2017**

**Qualification of palladium coated copper with gold flash (CuPdAu) bond wire and C194 lead frame material in selected products of the 150K wafer technology available in 20L QFN package at NSEB assembly site.**



## MICROCHIP PACKAGE QUALIFICATION REPORT

<b>Purpose</b>	Qualification of palladium coated copper with gold flash (CuPdAu) bond wire and C194 lead frame material in selected products of the 150K wafer technology available in 20L QFN package at NSEB assembly site.
<b>CN</b>	ES094303
<b>QUAL ID</b>	Q17038
<b>MP CODE</b>	C5BQ14G4XA00
<b>Part No.</b>	MCP23008-E/ML
<b>Bonding No.</b>	BDM-001185 Rev. A
<b>CCB No.</b>	2770
<b><u>Package</u></b>	
<b>Type</b>	20L QFN
<b>Package size</b>	4x4x0.9 mm
<b>Die thickness</b>	11 mils
<b>Die size</b>	47.20 x 55.60 mils
<b><u>Lead Frame</u></b>	
<b>Paddle size</b>	114 x 114 mils
<b>Material</b>	C194-FH
<b>Surface</b>	Ag on lead + Ag ring
<b>Process</b>	Etched
<b>Lead Lock</b>	Yes
<b>Part Number</b>	FR0995
<b>Treatment</b>	In-house roughening
<b><u>Material</u></b>	
<b>Epoxy</b>	8600
<b>Wire</b>	CuPdAu wire
<b>Mold Compound</b>	G700LTD
<b>Plating Composition</b>	Matte Tin



## MICROCHIP PACKAGE QUALIFICATION REPORT

### Manufacturing Information

Assembly Lot No.	Wafer Lot No.	Date Code
NSEB174100377.000	TMPE216205905.210	1701UG0
NSEB174100378.000	TMPE216205905.210	1701UG1
NSEB174200004.000	TMPE216205905.210	1702UEY

### Result

Pass  Fail  \_\_\_\_\_

20L QFN (4x4x0.9) assembled by UTL (NSEB) pass reliability test per QCI-39000. This package was qualified the Moisture/Reflow Sensitivity Classification Level 1 at 260°C reflow temperature per IPC/JEDEC J-STD-020D standard.

# PACKAGE QUALIFICATION REPORT

Test Number (Reference)	Test Condition	Standard/ Method	Qty. (Acc.)	Def/SS	Result	Remarks
<b>Moisture/Reflow Sensitivity Classification Test (At MSL Level 1)</b>	85°C/ 85%RH Moisture Soak 168 hrs. System: TABAI ESPEC Model PR-3SPH 3x Convection-Reflow 265°C max System: Vitronics Soltec MR1243  ( IPC/JEDEC J-STD-020D)	IPC/JEDEC C J-STD-020D	198	0/198	Pass	

<b><u>Precondition Prior Perform Reliability Tests</u></b> (At MSL Level 1)	<b>Electrical Test</b> :+25°C and 85°C System: J750	JESD22-A113	693(0)	693	Pass	Good Devices
	Bake 150°C, 24 hrs System: CHINEE			693		
	85°C/85%RH Moisture Soak 168 hrs. System: TABAI ESPEC Model PR-3SPH			693		
	3x Convection-Reflow 265°C max System: Vitronics Soltec MR1243			693		
	<b>Electrical Test</b> :+25°C and 85°C System: J750			0/693		

# PACKAGE QUALIFICATION REPORT

Test Number (Reference)	Test Condition	Standard/ Method	Qty. (Acc.)	Def/SS.	Result	Remarks
<b>Temp Cycle</b>	<b>Stress Condition:</b> (Standard) -65°C to +150°C, 500 Cycles System : TABAI ESPEC TSA-70H <b>Electrical Test:</b> + 85°C System: J750	JESD22-A104	231(0)	231 0/231	Pass	Parts had been pre-conditioned at 260°C
<b>UNBIASED-HAST</b>	<b>Stress Condition:</b> (Standard) +130°C/85%RH, 96 hrs. System: HAST 6000X <b>Electrical Test:</b> +25°C System: J750	JESD22-A118	231(0)	231 0/231	Pass	Parts had been pre-conditioned at 260°C  77 units / lot
<b>HAST</b>	<b>Stress Condition:</b> (Standard) +130°C/85%RH, 96 hrs. <b>Volt:</b> 5.0 Volts System: HAST 6000X <b>Electrical Test:</b> + 25°C and 85°C System: J750	<b>Bias</b> JESD22-A110	231(0)	231 0/231	Pass	Parts had been pre-conditioned at 260°C  77 units / lot
<b>High Temperature Storage Life</b>	<b>Stress Condition:</b> Bake 175°C, 504 hrs System: SHEL LAB <b>Electrical Test :</b> +25°C and 85°C System: J750	JESD22-A103	45(0)	45 0/45	Pass	45 units
<b>Bond Strength</b>	Wire Pull (>7.0 grams)	M2011	30 (0) Wires	0/30	Pass	
<b>Data Assembly</b>	Bond Shear (>15.00 grams)	JESD22-B116	30 (0) bonds	0/30	Pass	